

## **DS1667 Digital Resistor with OP AMP**

 $V_{CC}$ 

OUT0

SOUT

18

17

16

PIN ASSIGNMENT

2

3

NINV0

INV0

W1

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#### **FEATURES**

- Two digitally controlled 256-position potentiometers
- Serial port provides means for setting and reading both potentiometers
- Resistors can be connected in series to provide additional resolution
- amplifiers
- digital-to-analog converters, variable oscillators, and variable gain amplifiers

#### 11 15 RST Default wiper position on power up is 50% CLK 13 Resistive elements are temperature-12 OUT1 compensated to +20% end to end GND 10 Two high-gain, wide bandwidth operational 20-Pin DIP (300-mil) and 20-Pin SOIC See Mech Drawings Section Low power CMOS design Applications include analog-to-digital and PIN DESCRIPTION $V_{CC}$ - +5-Volt Supply **GND** - Ground 20-pin DIP package or optional 20-pin SOIC - Low End of Resistor surface mount package - High End of Resistor Operating temperature range - Wiper End of Resistor - Commercial: 0°C to 70°C - Substrate Bias and OP Resistance values: AMP Negative Supply SOUT - Wiper for Stacked -3 dB POINT RESOLUTION Configuration DS1667-10: 10k 39 ohms 1.1 MHz RST - Serial Port Reset Input DS1667-50: 50k 195 ohms 200 kHz DQ - Serial Port Input/Output DS1667-100: 100k 390 ohms **CLK** - Serial Port Clock Input **COUT** - Cascade Serial Port Output NINVO, NINVI - Noninverting OP AMP Input INVO, INVI - Inverting OP AMP Input OUTO, OUT1 - OP AMP Outputs

DESCRIPTION

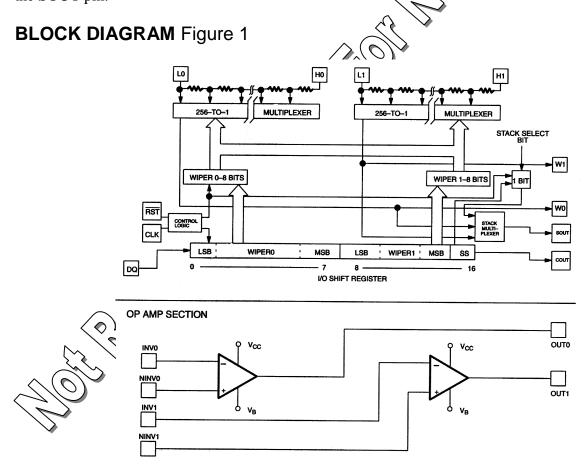
The DS1667 is a dual-solid state potentiometer that is adjustable by digitally selected resistive elements. Each potention eter is composed of 256 resistive elements. Between each resistive section of each potention ever are tap points accessible to the wiper. The position of the wiper on the resistive array is set by an 8-bit register that controls which tap point is connected to the wiper output. Each 8-bit register can be read or written by sending or receiving data bits over a 3-wire serial port. In addition, the resistors can be stacked such that a single potentiometer of 512 sections results. When two separate potentiometers are used, the resolution of the DS1667 is equal to the resistance value divided by 256. When the potentiometers are stacked end to end, the resistance value is doubled while the resolution remains the

same. The DS1667 also contains two high gain wide bandwidth operational amplifiers. Each amplifier has both the inverting and non-inverting inputs and the output available for user configuration. The operational amplifiers can be paired with the resistive elements to perform such functions as analog to digital conversion, digital to analog conversion, variable gain amplifiers, and variable oscillators.

#### **OPERATION - DIGITAL RESISTOR SECTION**

The DS1667 contains two potentiometers, each of which has its wiper set by a value contained in an 8-bit register (see Figure 1). Each potentiometer consists of 256 resistors of equal value with tap points between each resistor and at the low end.

In addition, the potentiometer can be stacked by connecting them in series such that the high end of potentiometer 0 is connected to the low end of potentiometer 1. When stacking potentiometers, the stack select bit is used to select which potentiometer wiper will appear at the stack multiplexer output (SOUT). A zero written to the stack multiplexer will connect wiper 0 to the SOUT pin. This wiper will determine which of the 256 bottom taps of the stacked potentiometer is selected. When a 1 is written to the stack multiplexer, wiper 1 is selected and one of the upper 256 taps of the stacked potentiometer is presented at the SOUT pin.



Information is written to and read from the wiper 0 and wiper 1 registers and the stack select bit via the 17-bit I/O shift register. The I/O shift register is serially loaded by a 3-wire serial port consisting of  $\overline{RST}$ , DQ, and CLK. It is updated by transferring all 17 bits (Figure 2). Data can be entered into the 17-bit shift register only when the  $\overline{RST}$  input is at a high level. While at a high level, the  $\overline{RST}$  function allows serial entry of data via the D/Q pin. The potentiometers always maintain their previous value until  $\overline{RST}$  is taken to a low level, which terminates data transfer. While  $\overline{RST}$  input is low, the DQ and CLK inputs are ignored.

Valid data is entered into the I/O shift register while RST is high on the low-to-high transition of the CLK input. Data input on the DQ pin can be changed while the clock input is high or low, but only data meeting the setup requirements will enter the shift register. Data is always entered starting with the value of the stack select bit. The next 8 bits to be entered are those specifying the wiper 1 setting. The MSB of these 8 bits is sent first. The next 8 bits to be entered are those specifying the wiper 0 setting, sent MSB first. The 17<sup>th</sup> bit to be entered, therefore, will be the least significant bit of the wiper 0 setting. If fewer than 17 bits are entered, the value of the potentiometer settings will result from the number of bits that were entered plus the remaining bits of the old value shifted over by the number of bits sent. If more than 17 bits are sent, only the last 17 bits are left in the shift register. Therefore, senting other than 17 bits can produce indeterminate potentiometer settings.

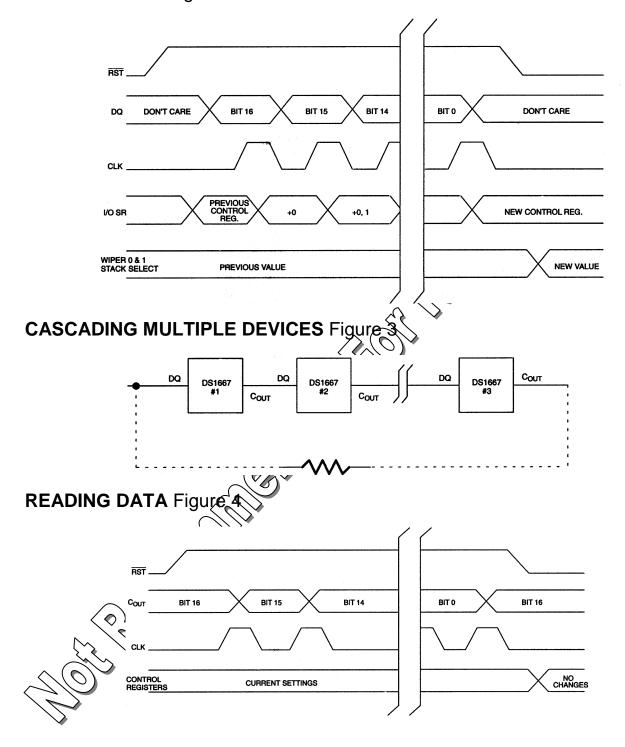
As bits are entered into the shift register, the previous value is shifted out bit by bit on the cascade serial port pin (COUT). By connecting the COUT pin to the DQ pin of a second DS1667, multiple devices can be daisy chained together as shown in Figure 3.

When connecting multiple devices, the total number of bits sent is always 17 times the number of DS1667s in the daisy chain. In applications where it is desirable to read the settings of potentiometers, the COUT pin of the last device connected in a daisy chain must be connected back to the DQ input of the first device through a resistor with a value of 1k to 10t. This resistor provides isolation between COUT and DQ when writing to the device (see Figure 3).

When reading data, the DQ line is left floating by the reading device. When RST is held low, bit 17 is always present on the COUT pin, which is reading device. The RST pin is then transitioned high to initiate a data transfer. When the CLK input transitions low to high, bit 17 is loaded into the first position of the I/O shift register and bit 16 becomes present on COUT and DQ. After 17 bits (or 17 times the number of devices for a daisy chain), the data has shifted completely around and back to its original position. When RST is transitioned back low to end data transfer, the value (the same as before the read occurred) is loaded into the wiper 0 and wiper 1 registers and the stack select bit.

When power is applied to the DS1667, the device always has the wiper settings at half position and the stack select bit is at 0.

## WRITING DATA Figure 2



#### **DS1667 LINEARITY MEASUREMENTS**

An important specification for the DS1667 is linearity, that is, for a given digital input, how close the analog output is to that which is expected.

The test circuit used to measure the linearity of the DS1667 is shown in Figure 5. Note that to get an accurate output voltage it is necessary to assure that the output current is 0, in order to negate the effects of wiper impedance RW, which is typically 400 ohms. For any given setting N for the pot, the expected voltage output at SOUT is:

$$VO = -5 + [10 \text{ X} (N/256)] \text{ (in volts)}$$

Absolute linearity is a comparison of the actual measured output voltage versus the expected value given by the equation above and is given in terms of an LSB, which is the change in expected output when the digital input is incremented by 1. In this case the LSB is 10/256 or 0.03906 volts. The equation for the absolute linearity of the DS1667 is:

$$\frac{\text{Vo (actual) - Vo (expected)}}{\text{LSB}} = \text{All in SBs}$$

The specification for absolute linearity of the DS1667 is USB typical.

Relative linearity is a comparison of the difference of actual output voltages of two successive taps and the difference of the expected output voltages of two successive taps. The expected difference of output voltages is 1 LSB or 0.03906V for the measurement system of Figure 5. Relative linearity is expressed in terms of an LSB and is given by the equation:

$$\frac{\text{No (actual)} - \text{LSB}}{\text{LSB}} = \text{RL}$$

The specification for relative linearity of the DS1667 is  $\pm$  0.5 LSB typical.

Figure 6 is a plot of absolute linearity (AL) and relative linearity (RL) versus wiper setting for a typical DS1667 at 25°C.

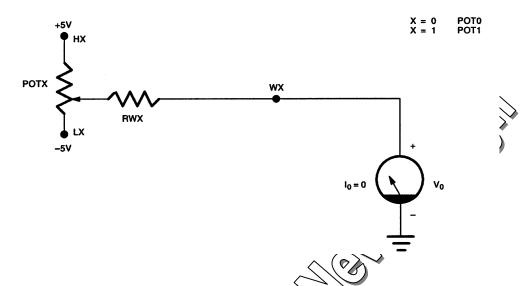
### DESCRIPTION AND OPERATION - OP AMP SECTION

The DS1667 centains two operational amplifiers which are ideal for operation from a single 5V supply and ground or from +5V supplies (see Figure 1). An internal resistor divider defines the internal reference of the operation to be halfway between the power supplies, i.e.:

$$\frac{V_{DD} + V_B}{2}$$

For optimal performance, choose analog ground to be this value. The operational amplifiers feature rail to rail output swing in addition to an input common mode range that includes the positive rail. Performance features include broad band noise immunity as well as voltage gain into realistic loads specified at both 600 ohms and 2k ohms. High voltage gain is produced with low input offset voltage and low offset voltage drift. Current consumption is less than 1.9 mA per amplifier and the device is virtually immune to latchup.

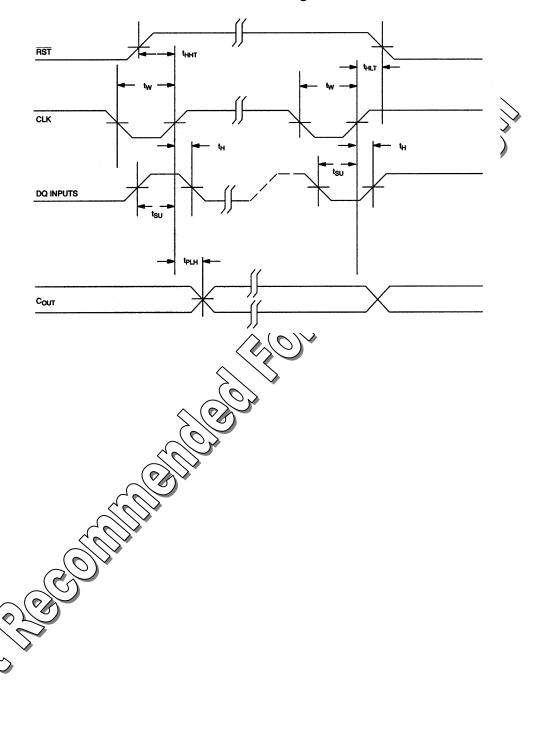
## **LINEARITY MEASUREMENT CONFIGURATION** Figure 5



# DS1667 ABSOLUTE AND RELATIVE LINEARITY Figure 6 Absolute and Relative Linearity (Normalized to 198)

8.0 0.6 0.4 0.2 -0.2 -0.4 -0.6 -0.8 50 500 100 150 350 200 250 400 450 Wiper Setting

## **TIMING DIAGRAM: RESISTOR SECTION Figure 7**



#### **ABSOLUTE MAXIMUM RATINGS\***

 $\begin{array}{lll} \mbox{Voltage on Any Pin Relative to Ground ($V_B = GND$)} & -0.5V \ \mbox{to } +7.0V \\ \mbox{Voltage on Resistor Pins when $V_B = -5.5V$} & -5.5V \ \mbox{to } +7.0V \\ \mbox{Voltage on $V_B$} & -5.5V \ \mbox{to } GND \\ \mbox{Operating Temperature} & 0^{\circ}\mbox{C to } 70^{\circ}\mbox{C} \\ \mbox{Storage Temperature} & -55^{\circ}\mbox{C to } +125^{\circ}\mbox{C} \\ \mbox{Soldering Temperature} & 260^{\circ}\mbox{C for } 10 \ \mbox{second } \mbox{Soldering } \mbox{Temperature} \\ \mbox{Soldering Temperature} & -55^{\circ}\mbox{C for } 10 \ \mbox{second } \mbox{Soldering } \mbox{Temperature} \\ \mbox{Soldering Temperature} & -55^{\circ}\mbox{C for } 10 \ \mbox{second } \mbox{Soldering } \mbox{Soldering } \mbox{Temperature} \\ \mbox{Soldering Temperature} & -55^{\circ}\mbox{C for } 10 \ \mbox{second } \mbox{Soldering } \$ 

\* This is a stress rating only and functional operation of the device at these or any other conditions

above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

## RECOMMENDED DC OPERATING CONDITIONS RESISTOR SECTION

(0°C to 70°C)

PARAMETER	SYMBOL	MIN	TXX	MAX	UNITS	NOTES
Positive Supply Voltage	$V_{CC}$	+4.5	1500	5.5	V	1
Input Logic 1	$V_{\mathrm{IH}}$	2.0	1	$V_{CC} + 0.5$	V	1
Input Logic 0	$V_{ m IL}$	-0.5%	$\nearrow$	+0.8	V	1
Negative Supply Voltage	$V_{\mathrm{B}}$	\ \forall \( \sigma \)		GND	V	1
Resistor Inputs	L, H, W	VB DE		V <sub>CC</sub> +0.5	V	2

### DC ELECTRICAL CHARACTERISTICS

**RESISTOR SECTION** ( $0^{\circ}C + 0^{\circ} = 5.0 \text{V} \pm 10\%$ ,  $V_B = -5.0 \text{V} \pm 10\%$ )

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Positive Supply Current			3	5	mA	
Negative Supply Current	) B		3	5	mA	
Input Leakage	$I_{\rm U}$	-1		+1	μA	
Wiper Resistance	$ ightarrow$ $R_{ m W}$		400	1000	ohms	
Wiper Current	$I_{ m W}$			1	mA	
Output Leakage	$I_{LO}$	-1		+1	μA	
Logic 1 Output @ 2.4 Works	$I_{OH}$	-1.0			mA	
Logic 0 Output @ 0.4 Volts	$I_{OL}$			4	mA	
End-to-End-Resistor Tolerance	$TOL_R$	-20		+20	%	9
Noise (ref: W)	N		-120		dB	
W 2					$\sqrt{\text{Hz}}$	
Absolute Linearity	AL		1.0		LSB	
Relative Linearity	RL		0.5		LSB	
Resistor Temperature	$TC_R$		750		ppm	
Coefficient					$\frac{\text{ppm}}{^{\circ}\text{C}}$	

#### CAPACITANCE

 $(T_{\Lambda} = 25^{\circ}C)$ 

					\ - /	<u> </u>
PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Input Capacitance	$C_{IN}$			5	pF	
Output Capacitance	$C_{OUT}$			7	pF	

## AC ELECTRICAL CHARACTERISTICS RESISTOR SECTION

RESISTOR SECTION	$(0^{\circ}\text{C to } 70^{\circ}\text{C}, V_{\text{CC}} = 5\text{V} \pm 10\%)$
	(3 3 13 3 7 100 31 = 1373

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
CLK Frequency	$f_{CLK}$			10	MHz	
Width of CLK Pulse	$t_{ m W}$	50			ns	
Data Setup Time	$t_{ m SU}$	30			ns	
Data Hold Time	$t_{\mathrm{H}}$	10			\020 \	
Propagation Delay Time Low	$t_{\rm PLH}$			50 众	(cns)	3
to High Level Clock to Output						
RST High to Clock Input High	$t_{ m HHT}$	50			) ns	
RST Low from	$t_{ m HLT}$	50			ns	
Clock Input High				10)		

## OPERATIONAL AMPLIFIER SECTION DC ELECTRICAL CHARACTERISTICS

 $(0^{\circ}\text{C to } 70^{\circ}\text{C}; V_{CC} = 5.0\text{V} \pm 10\%, V_{B} = -5.0\text{V} \pm 10\%)$ 

	(0 C 10	70 C, VC	C = C + C V	~± 1070,	$v_B = -5.0$	V = 10%
PARAMETER	SYMBOL	MIN	ZYYP	MAX	UNITS	NOTES
Input Offset Voltage	$V_{OS}$	^	1	10	mV	
Input Offset Voltage Drift	$V_{\mathrm{OSD}}$		10		uV/°C	
Common Mode Rejection	$CM_R$	$\mathcal{N}(\mathcal{O})$	62		dB	
Positive Power	↓DC ^	$\sim$	62		dB	
Supply Rejection	$+PS_R \searrow$	$\langle \rangle$	02		uБ	
Negative Power	DC	<b>&gt;</b>	62		dB	
Supply Rejection	-PS(P)		02		uБ	
Input Common	02	V <sub>B</sub> +1.5V		$V_{CC}$	V	
Mode Voltage Range	100m	V B+1.3 V		V CC	V	
Large Signal Voltage Gain			106		dB	$R_L=2k\Omega$
Large Signal Voltage Gain			96		dB	$R_L=600k\Omega$
Output Swing	$V_{SWGH}$	4.6	4.7		V	$R_L=2k\Omega$
			4.7	16	V	to GND
Output Swing	$V_{ m SWGL}$		-4.7	-4.6	<b>v</b>	$V_B = -5V$
Output Swing	$V_{SWGH}$	4.5	4.6		V	$R_L=600k\Omega$
	V		16	15	V	to GND
Output Swing	$V_{ m SWGL}$		-4.6	-4.5	V	$V_{\rm B} = -5V$
Output Current	V <sub>O,SOURCE</sub>	13	58		mA	$V_O = 0V$
Output Current	V <sub>O,SINK</sub>	13	63		mA	$V_{\rm O} = +5V$

## OPERATIONAL AMPLIFIER SECTION AC ELECTRICAL CHARACTERISTICS

 $(0^{\circ}\text{C to } 70^{\circ}\text{C}; V_{\text{CC}} = 5.0\text{V} \pm 10\%)$ 

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Slew Rate	$ m V_{SL}$	0.7	2		V/µs	6
Gain Bandwidth Product	GBP		2.5		MHz	5
Phase Margin	PM		75		deg	5
Gain Margin	GM		20		(IB)	5
Amp-to-Amp Isolation	AAI		130	$\Diamond$	COBS	
Input Referred Voltage Noise	IRVF		100		n Voltz	F=1 kHz
Input Referred Current Noise	IRV1		0.0002		$A/\sqrt{Hz}$	F=1 kHz
						F=10 kHz
Total Harmonic Distortion	HD		0.1		%	AV=-10
						RL=2kΩ
						$V_{O} = 1V_{PP}$

### **NOTES:**

- 1. All voltages are referenced to ground.
- 2. Resistor inputs cannot exceed the substrate bias voltage in the negative direction.
- 3. Measured with a load as shown in Figure 8
- 4. Over a frequency range of 0 1 kHz.
- 5. Load is  $R_L = 600 \Omega C_L = 10 \text{ pF}$ .
- 6.  $V_{DD} = +5.0 \text{V V}_B = -5.0 \text{V}$  connected as voltage follower with 10V step input and  $R_L = \infty$ .
- 7. To achieve best op amp performance,  $V_{DD} = +5.0 \text{V V}_B = -5.0 \text{V}$  and analog ground = 0 V. In general analog ground =  $\frac{V_{DD} + V_B}{2}$
- 8. OP AMPS idle, no toad.
- 9. Valid at 25°C only

## LOAD SCHEMATIC Figure 8

